

TOSHIBA Transistor    Silicon NPN Epitaxial Type (Darlington Power Transistor)

2SD2206

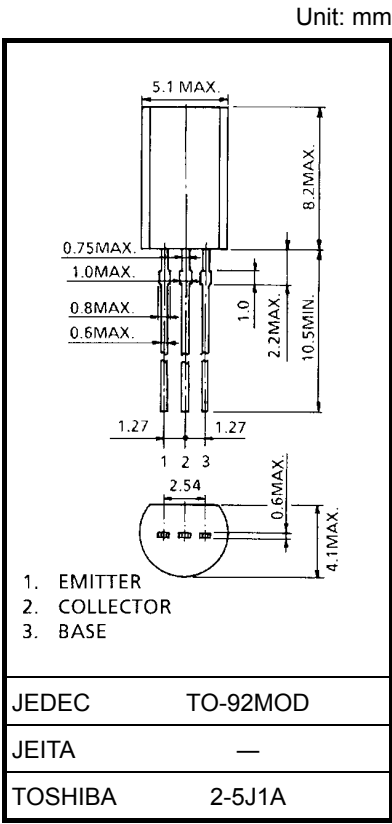
Micro Motor Drive, Hammer Drive Applications  
Switching Applications  
Power Amplifier Applications

- High DC current gain:  $h_{FE} = 2000$  (min) ( $V_{CE} = 2\text{ V}$ ,  $I_C = 1\text{ A}$ )
- Low saturation voltage:  $V_{CE(sat)} = 1.5\text{ V}$  (max) ( $I_C = 1\text{ A}$ ,  $I_B = 1\text{ mA}$ )

Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

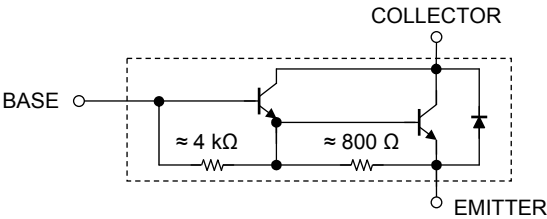
Characteristics		Symbol	Rating	Unit
Collector-base voltage		$V_{CBO}$	100	V
Collector-emitter voltage		$V_{CEO}$	100	V
Emitter-base voltage		$V_{EBO}$	8	V
Collector current	DC	$I_C$	2	A
	Pulse	$I_{CP}$	3	
Base current		$I_B$	0.5	A
Collector power dissipation		$P_C$	900	mW
Junction temperature		$T_j$	150	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to 150	$^{\circ}\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

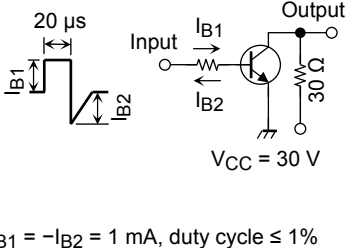


Weight: 0.36 g (typ.)

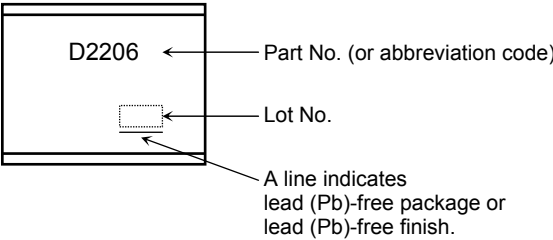
Equivalent Circuit

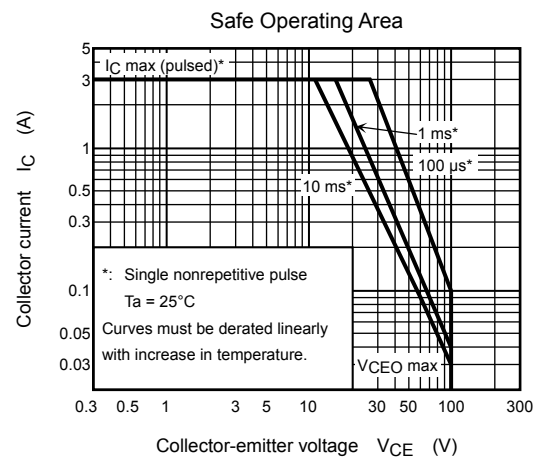
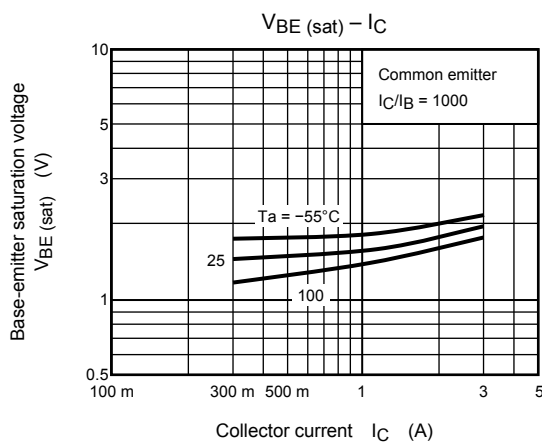
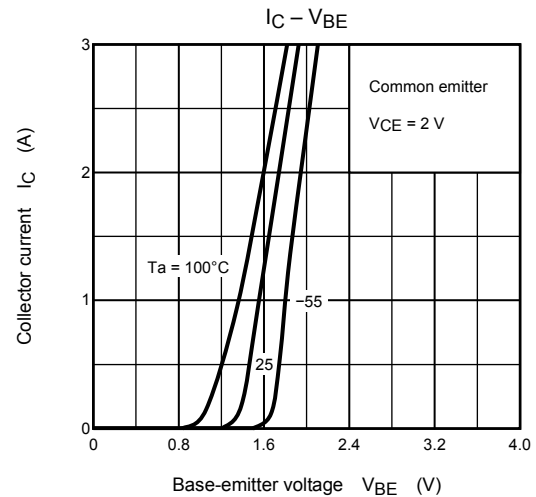
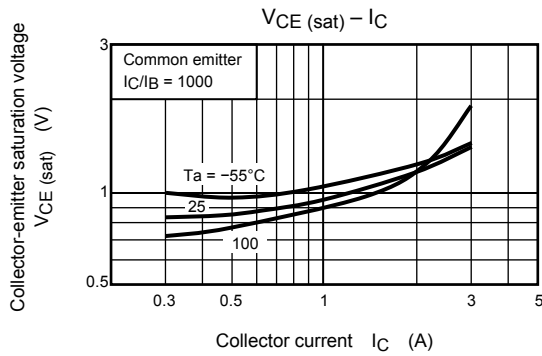
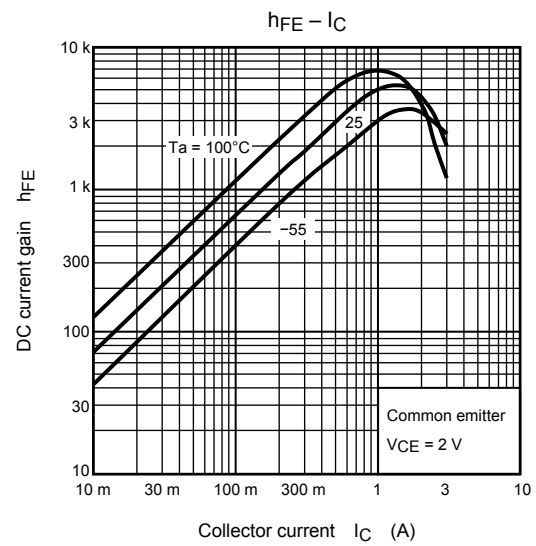
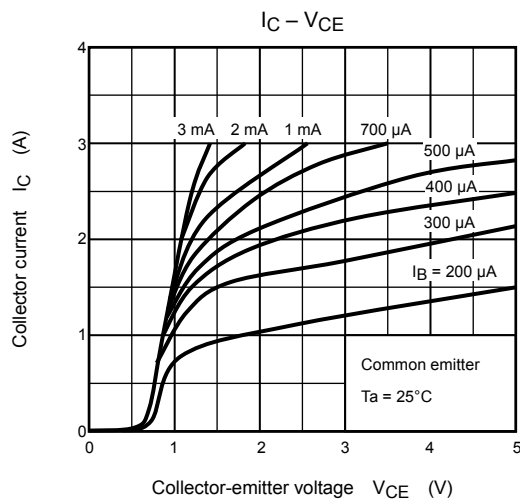


Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		$I_{CBO}$	$V_{CB} = 80\text{ V}, I_E = 0$	—	—	10	$\mu\text{A}$
Emitter cut-off current		$I_{EBO}$	$V_{EB} = 8\text{ V}, I_C = 0$	—	—	4	$\text{mA}$
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 10\text{ mA}, I_B = 0$	100	—	—	$\text{V}$
DC current gain		$h_{FE}$	$V_{CE} = 2\text{ V}, I_C = 1\text{ A}$	2000	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	1.5	$\text{V}$
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	2.0	$\text{V}$
Transition frequency		$f_T$	$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$	—	100	—	$\text{MHz}$
Collector output capacitance		$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	20	—	$\text{pF}$
Switching time	Turn-on time	$t_{on}$	 $I_{B1} = -I_{B2} = 1\text{ mA}, \text{duty cycle} \leq 1\%$	—	0.4	—	$\mu\text{s}$
	Storage time	$t_{stg}$		—	4.0	—	
	Fall time	$t_f$		—	0.6	—	

Marking





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